
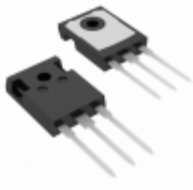
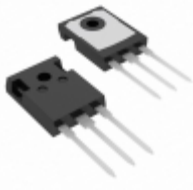
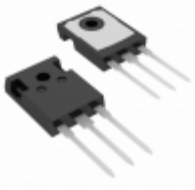
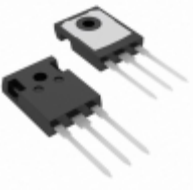



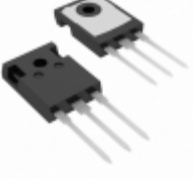
	<h2 style="color: red;">FQH44N10</h2>
	<b>Hersteller-Teilenummer:</b> <a href="#">FQH44N10</a>
	<b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a>
	<b>Teil der Beschreibung:</b> MOSFET N-CH 100V 48A TO-247
	<b>Datenblätter:</b>  <a href="#">FQH44N10.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 32742 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQH44N10</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 100V 48A TO-247
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	32742 pcs Stock
detaillierte Beschreibung	N-Channel 100V 48A (Tc) 180W (Tc) Through Hole
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-247-3
Supplier Device-Gehäuse	TO-247
Verlustleistung (max)	180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	48A (Tc)
Rds On (Max) @ Id, Vgs	39 mOhm @ 24A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	62nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1800pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)

FQH44N10 ist neu im Original, Suche FQH44N10 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQH44N10 AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage FQH44N10: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQH44N10-F133</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>	 <p><b>FQH70N10</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 70A TO-247</p>	 <p><b>FQH140N10</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 140A TO-247</p>	 <p><b>FQH18N50V2</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 500V 20A TO-247</p>
 <p><b>FQH18N50U2</b> FARICILD FQH18N50U2 FARICILD</p>	 <p><b>FQH44N10_F133</b> Fairchild/ON Semiconductor FQH44N10_F133 Fairchild/ON Semiconductor</p>	 <p><b>FQH140N10</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 100V 140A TO-247</p>	 <p><b>FQH44N10</b> Fairchild/ON Semiconductor MOSFET N-CH 100V 48A TO-247</p>

### heiße Teile

Mehr

06035A330FAT2A	08051C473KAT2A	AM26LS32SC	D B1212S-W25	B521F-2T
B82432T1103K	BAW56DW-7-F	D BU4945G-TR	BZX84C27-E3-08	CBC2016T220K
CGA6M3X7R1H225M200AE	CL31C331JBCNNNC	CMSD6263A	D1481N60T	D428N20T
D EVK105CH0R7BW-F	FAN3216TMX	FQH44N10	FQH44N10_F133	FQH70N15
FQH8N100C	FQH8N100C	G2501K81D	GRM0335C1E2R0CD01J	GRM2197U2A181JZ01D
HEW1142LS-TR	HMC183QS24	D IPB038N08N3G	LD05YC103KAB2A	LT1117CST-3.3TR#TRPB
LTC1064-3CS	D LTE-329P4-M	LV8011V-TLM-E	MAX13085EESA	MAX16832CASA+T
MAX6062AEUR+T	MAX690ACSA+T	MP62071-13	MPQ20051DQ-LF-Z	OP296HRUZ-REEL
PDTA143XT	PE-0603CD010KTT	PI74AVC164245KE	D RFSW8008TR7	SI8920AC-IP
SKKT430/02E	SMBSAC5.0-TP	SPB47N10	ST60-36P	UM3232EEUE

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited